

HiPerFET™ Power MOSFETs Q Class

N-Channel Enhancement Mode
Avalanche Rated
Low Q_g , High dv/dt

Preliminary data sheet

IXFH 12N90Q
IXFT 12N90Q

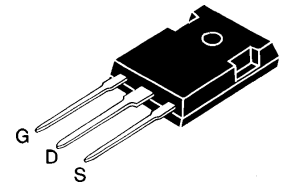
$V_{DSS} = 900 \text{ V}$
 $I_{D25} = 12 \text{ A}$
 $R_{DS(on)} = 0.9 \Omega$

$t_{rr} \leq 200 \text{ ns}$

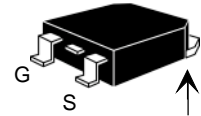


| Symbol | Test Conditions | Maximum Ratings | |
|-----------|---|-----------------|------------------|
| V_{DSS} | $T_J = 25^\circ\text{C}$ to 150°C | 900 | V |
| V_{DGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GS} = 1 \text{ M}\Omega$ | 900 | V |
| V_{GS} | Continuous | ± 20 | V |
| V_{GSM} | Transient | ± 30 | V |
| I_{D25} | $T_C = 25^\circ\text{C}$ | 12 | A |
| I_{DM} | $T_C = 25^\circ\text{C}$, pulse width limited by T_{JM} | 48 | A |
| I_{AR} | $T_C = 25^\circ\text{C}$ | 12 | A |
| E_{AR} | $T_C = 25^\circ\text{C}$ | 30 | mJ |
| dv/dt | $I_S \leq I_{DM}$, $di/dt \leq 100 \text{ A}/\mu\text{s}$, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ\text{C}$, $R_G = 2 \Omega$ | 5 | V/ns |
| P_D | $T_C = 25^\circ\text{C}$ | 300 | W |
| T_J | | -55 ... +150 | $^\circ\text{C}$ |
| T_{JM} | | 150 | $^\circ\text{C}$ |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ |
| T_L | 1.6 mm (0.063 in) from case for 10 s | 300 | $^\circ\text{C}$ |
| M_d | Mounting torque | 1.13/10 | Nm/lb.in. |
| Weight | TO-247 AD | 6 | g |
| | TO-268 | 4 | g |

TO-247 AD (IXFH)



TO-268 (D3) (IXFT)



G = Gate D = Drain
S = Source TAB = Drain

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|--------------|--|---|------|----------------------|
| | | min. | typ. | max. |
| V_{DSS} | $V_{GS} = 0 \text{ V}$, $I_D = 3 \text{ mA}$ | 900 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 4 \text{ mA}$ | 2.5 | | V |
| I_{GSS} | $V_{GS} = \pm 20 \text{ V}_{DC}$, $V_{DS} = 0$ | | | $\pm 100 \text{ nA}$ |
| I_{DSS} | $V_{DS} = 0.8 \cdot V_{DSS}$ $V_{GS} = 0 \text{ V}$ | $T_J = 25^\circ\text{C}$ | | 50 μA |
| | | $T_J = 125^\circ\text{C}$ | | 1 mA |
| $R_{DS(on)}$ | $V_{GS} = 10 \text{ V}$, $I_D = 0.5 I_{D25}$ Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2 \%$ | | | 0.9 Ω |

Features

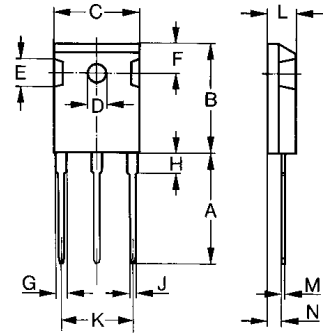
- IXYS advanced low Q_g process
- Low gate charge and capacitances
 - easier to drive
 - faster switching
- International standard packages
- Low $R_{DS(on)}$
- Unclamped Inductive Switching (UIS) rated
- Molding epoxies meet UL 94 V-0 flammability classification

Advantages

- Easy to mount
- Space savings
- High power density

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|--------------|--|---|------|------|
| | | min. | typ. | max. |
| g_{fs} | $V_{DS} = 10\text{ V}; I_D = 0.5 \cdot I_{D25}$, pulse test | 6 | 10 | S |
| C_{iss} | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$ | | 2900 | pF |
| C_{oss} | | | 315 | pF |
| C_{rss} | | | 50 | pF |
| $t_{d(on)}$ | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ $R_G = 2\ \Omega$ (External), | | 20 | ns |
| t_r | | | 23 | ns |
| $t_{d(off)}$ | | | 40 | ns |
| t_f | | | 15 | ns |
| $Q_{g(on)}$ | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ | | 90 | nC |
| Q_{gs} | | | 30 | nC |
| Q_{gd} | | | 40 | nC |
| R_{thJC} | (TO-247) | | 0.42 | K/W |
| R_{thCK} | | | 0.25 | K/W |

TO-247 AD (IXFH) Outline

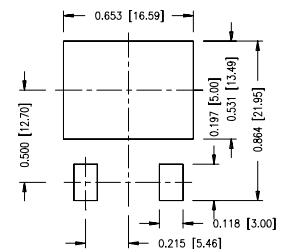


| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 19.81 | 20.32 | 0.780 | 0.800 |
| B | 20.80 | 21.46 | 0.819 | 0.845 |
| C | 15.75 | 16.26 | 0.610 | 0.640 |
| D | 3.55 | 3.65 | 0.140 | 0.144 |
| E | 4.32 | 5.49 | 0.170 | 0.216 |
| F | 5.4 | 6.2 | 0.212 | 0.244 |
| G | 1.65 | 2.13 | 0.065 | 0.084 |
| H | - | 4.5 | - | 0.177 |
| J | 1.0 | 1.4 | 0.040 | 0.055 |
| K | 10.8 | 11.0 | 0.426 | 0.433 |
| L | 4.7 | 5.3 | 0.185 | 0.209 |
| M | 0.4 | 0.8 | 0.016 | 0.031 |
| N | 1.5 | 2.49 | 0.087 | 0.102 |

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|----------|---|---|------|---------------|
| | | min. | typ. | max. |
| I_S | $V_{GS} = 0\text{ V}$ | | | 12 A |
| I_{SM} | Repetitive; pulse width limited by T_{JM} | | | 48 A |
| V_{SD} | $I_F = I_S, V_{GS} = 0\text{ V}$, Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $d \leq 2\%$ | | | 1.3 V |
| t_{rr} | $I_F = I_S, -di/dt = 100\text{ A}/\mu\text{s}, V_R = 100\text{ V}$ | | 200 | ns |
| Q_{RM} | | | 0.6 | μC |
| I_{RM} | | | 7 | A |

| TO-268AA (D ³ PAK) | | Dim. | | Millimeter | | Inches | |
|-------------------------------|----------------|----------|-------|------------|------|--------|------|
| | | | | Min. | Max. | Min. | Max. |
| | A | 4.9 | 5.1 | .193 | .201 | | |
| | A ₁ | 2.7 | 2.9 | .106 | .114 | | |
| | A ₂ | .02 | .25 | .001 | .010 | | |
| | b | 1.15 | 1.45 | .045 | .057 | | |
| | b ₂ | 1.9 | 2.1 | .75 | .83 | | |
| | C | .4 | .65 | .016 | .026 | | |
| | D | 13.80 | 14.00 | .543 | .551 | | |
| | E | 15.85 | 16.05 | .624 | .632 | | |
| | E ₁ | 13.3 | 13.6 | .524 | .535 | | |
| | e | 5.45 BSC | | .215 BSC | | | |
| | H | 18.70 | 19.10 | .736 | .752 | | |
| | L | 2.40 | 2.70 | .094 | .106 | | |
| | L ₁ | 1.20 | 1.40 | .047 | .055 | | |
| | L ₂ | 1.00 | 1.15 | .039 | .045 | | |
| | L ₃ | 0.25 BSC | | .010 BSC | | | |
| | L ₄ | 3.80 | 4.10 | .150 | .161 | | |

Min. Recommended Footprint





Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.